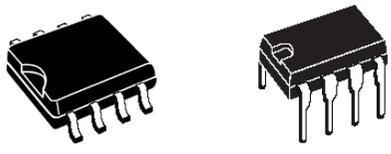
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VIPer12ADIP - E
VIPer12AS - E

Low Power OFF-Line SMPS Primary Switcher

Features

- Fixed 60kHZ Switching Frequency
- 9V to 38V Wide Range V_{DD} Voltage
- Current Mode Control
- Auxiliary Undervoltage Lockout with Hysteresis
- High Voltage Start-up Current Source
- Overtemperature, Overcurrent and Overvoltage Protection with Auto-Restart
- Typical power capability
  - European (195 - 265 Vac) 8W for SO-8, 13W for DIP-8
  - European (85 - 265 Vac) 5W for SO-8, 8W for DIP-8



SO-8 **DIP-8**

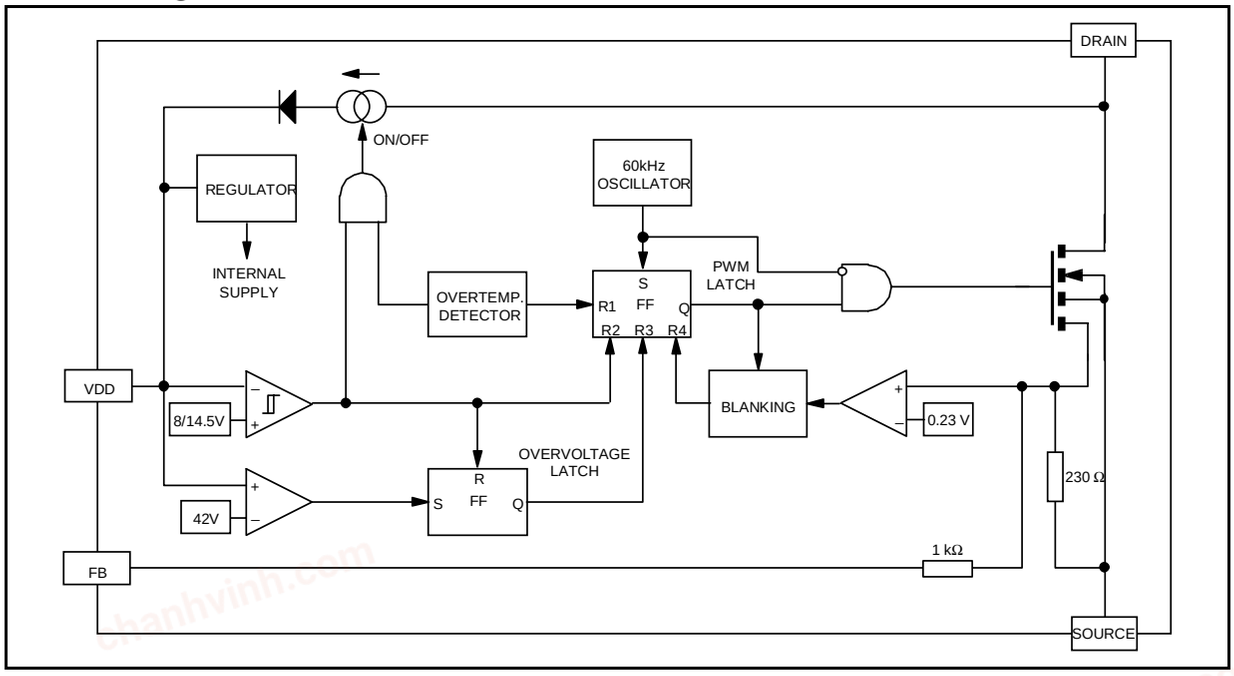
Typical applications cover off line power supplies for battery charger adapters, standby power supplies for TV or monitors, auxiliary supplies for motor control, etc.
The internal control circuit offers the following benefits:

- Large input voltage range on the V_{DD} pin accommodates changes in auxiliary supply voltage. This feature is well adapted to battery charger adapter configurations.
- Automatic burst mode in low load condition.
- Overvoltage protection in HICCUP mode.

Description

The VIPer12A combines a dedicated current mode PWM controller with a high voltage Power MOSFET on the same silicon chip.

Block diagram



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1 Electrical data

1.1 Maximum rating

Stressing the device above the rating listed in the “Absolute Maximum Ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
$V_{DS(sw)}$	Switching drain source voltage (T_J = 25 ... 125°C) *Note 1*	-0.3 ... 730	V
$V_{DS(st)}$	Start-up drain source voltage (T_J = 25 ... 125°C) *Note 2*	-0.3 ... 400	V
I_D	Continuous drain current	Internally limited	A
V_{DD}	Supply voltage	0 ... 50	V
I_{FB}	Feedback current	3	mA
V_{ESD}	Electrostatic discharge: Machine model (R = 0Ω; C = 200pF) Charged device model	 200 1.5	 V kV
T_J	Junction operating temperature	Internally limited	°C
T_C	Case operating temperature	-40 to 150	°C
T_{stg}	Storage Temperature	-55 to 150	°C

Note: 1 This parameter applies when the start-up current source is OFF. This is the case when the V_{DD} voltage has reached V_{DDon} and remains above V_{DDoff}.

2 This parameter applies when the start up current source is on. This is the case when the V_{DD} voltage has not yet reached V_{DDon} or has fallen below V_{DDoff}.

1.2 Thermal data

Table 2. Thermal data

Symbol	Parameter		SO-8	DIP-8	Unit
R_{thJC}	Thermal Resistance Junction-case	Max	25	15	°C/W
R_{thJA}	Thermal Resistance Ambient-case (1)	Max	55	45	°C/W

1. When mounted on a standard single-sided FR4 board with 200 mm^2 of Cu (at least 35 µm thick) connected to all DRAIN pins.

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2 Electrical characteristics

T_J = 25°C, V_{DD} = 18V, unless otherwise specified

Table 3. Power section

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-source voltage	I_D = 1mA; V_{FB} = 2V	730			V
I_{DSS}	OFF State drain current	V_{DS} = 500V; V_{FB} = 2V; T_J = 125°C			0.1	mA
$r_{DS(on)}$	Static drain-source ON state resistance	I_D = 0.2A I_D = 0.2A; T_J = 100°C		27	30 54	Ω
t_f	Fall time	I_D = 0.1A; V_{IN} = 300V *Note 1* (See *Figure 8 on page 13*)		100		ns
t_r	Rise time	I_D = 0.2A; V_{IN} = 300V *Note 1* (See *Figure 8 on page 13*)		50		ns
C_{OSS}	Drain capacitance	V_{DS} = 25V		40		pF

Note: 1 On clamped inductive load

Table 4. Supply section

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{DDch}	Start-up charging current	V_{DS} = 100V; V_{DD} = 5V ...V_{DDon} (See *Figure 9 on page 13*)		-1		mA
I_{DDoff}	Start-up charging current in thermal shutdown	V_{DD} = 5V; V_{DS} = 100V $T_J > T_{SD} - T_{HYST}$	0			mA
I_{DD0}	Operating supply current not switching	I_{FB} = 2mA		3	5	mA
I_{DD1}	Operating supply current switching	I_{FB} = 0.5mA; I_D = 50mA *Note 2*		4.5		mA
D_{RST}	Restart duty-cycle	(See *Figure 10 on page 13*)		16		%
V_{DDoff}	V_{DD} Undervoltage shutdown threshold	(See *Figure 9*, *Figure 10 on page 13*)	7	8	9	V
V_{DDon}	V_{DD} Start-up threshold	(See *Figure 9*, *Figure 10 on page 13*))	13	14.5	16	V
V_{DDhyst}	V_{DD} Threshold hysteresis	(See *Figure 9 on page 13*)	5.8	6.5	7.2	V
V_{DDovp}	V_{DD} Overvoltage threshold		38	42	46	V

2 These test conditions obtained with a resistive load are leading to the maximum conduction time of the device.

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Table 5. Oscillation section

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
F_{OSC}	Oscillator frequency total variation	$V_{DD} = V_{DDoff}$ ... 35V; T_J = 0 ... 100°C	54	60	66	kHz

Table 6. PWM Comparator section

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
G_{ID}	I_{FB} to I_D current gain	(See *Figure 11 on page 14*)		320		
I_{Dlim}	Peak current limitation	V_{FB} = 0V (See *Figure 11 on page 14*)	0.32	0.4	0.48	A
I_{FBsd}	I_{FB} Shutdown current	(See *Figure 11 on page 14*)		0.9		mA
R_{FB}	FB Pin input impedance	I_D = 0mA (See *Figure 11 on page 14*)		1.2		kΩ
t_d	Current sense delay to turn-OFF	I_D = 0.2A		200		ns
t_b	Blanking time			500		ns
t_{ONmin}	Minimum Turn-ON time			700		ns

Table 7. Overtemperature section

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
T_{SD}	Thermal shutdown temperature	(See *Figure 12 on page 14*)	140	170		°C
T_{HYST}	Thermal shutdown hysteresis	(See *Figure 12 on page 14*)		40		°C

Table 8. Typical Power Capability

Mains type	SO-8	DIP-8
European (195 - 265 Vac)	8W	13W
US / Wide range (85 - 265 Vac)	5W	8W

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3 Pin connections and function

Figure 1. Pin connection

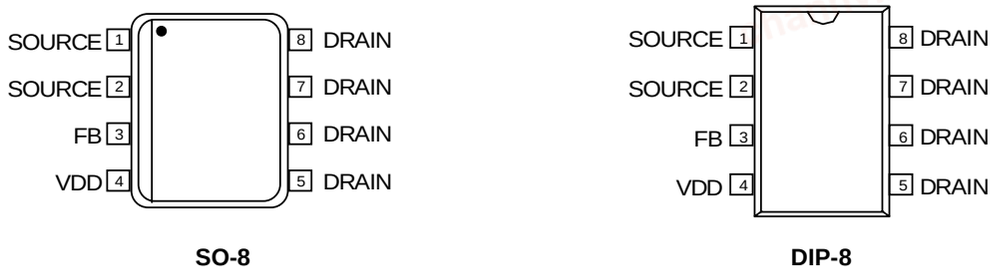


Figure 2. Current and voltage conventions

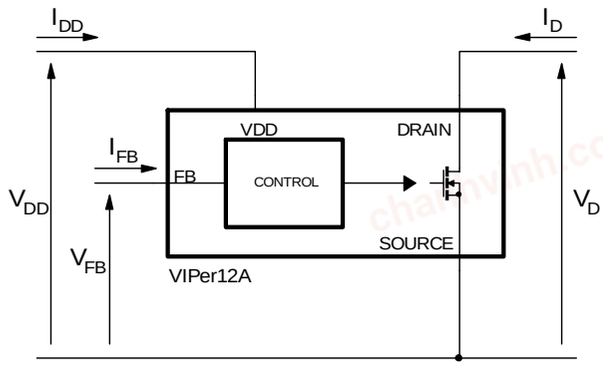


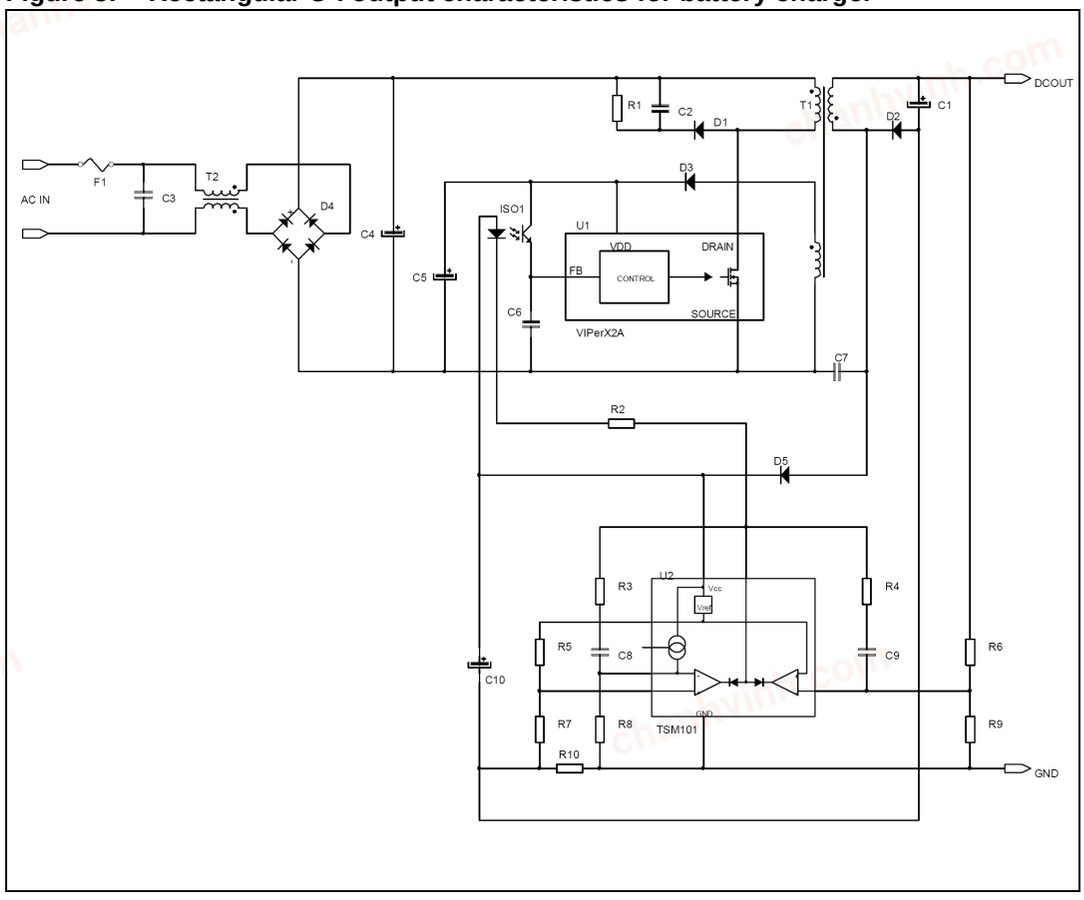
Table 9. Pin function

Pin Name	Pin Function
V_{DD}	Power supply of the control circuits. Also provides a charging current during start up thanks to a high voltage current source connected to the drain. For this purpose, an hysteresis comparator monitors the V_{DD} voltage and provides two thresholds: - V_{DDon}: Voltage value (typically 14.5V) at which the device starts switching and turns off the start up current source. - V_{DDoff}: Voltage value (typically 8V) at which the device stops switching and turns on the start up current source.
SOURCE	Power MOSFET source and circuit ground reference.
DRAIN	Power MOSFET drain. Also used by the internal high voltage current source during start up phase for charging the external V_{DD} capacitor.
FB	Feedback input. The useful voltage range extends from 0V to 1V, and defines the peak drain MOSFET current. The current limitation, which corresponds to the maximum drain current, is obtained for a FB pin shorted to the SOURCE pin.

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4 Rectangular U-I Output characteristics

Figure 3. Rectangular U-I output characteristics for battery charger



A complete regulation scheme can achieve combined and accurate output characteristics. *Figure 3.* presents a secondary feedback through an optocoupler driven by a TSM101. This device offers two operational amplifiers and a voltage reference, thus allowing the regulation of both output voltage and current. An integrated OR function performs the combination of the two resulting error signals, leading to a dual voltage and current limitation, known as a rectangular output characteristic. This type of power supply is especially useful for battery chargers where the output is mainly used in current mode, in order to deliver a defined charging rate. The accurate voltage regulation is also convenient for Li-ion batteries which require both modes of operation.

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5 Wide range of V_{DD} voltage

The V_{DD} pin voltage range extends from 9V to 38V. This feature offers a great flexibility in design to achieve various behaviors. In *Figure 3 on page 7* a forward configuration has been chosen to supply the device with two benefits:

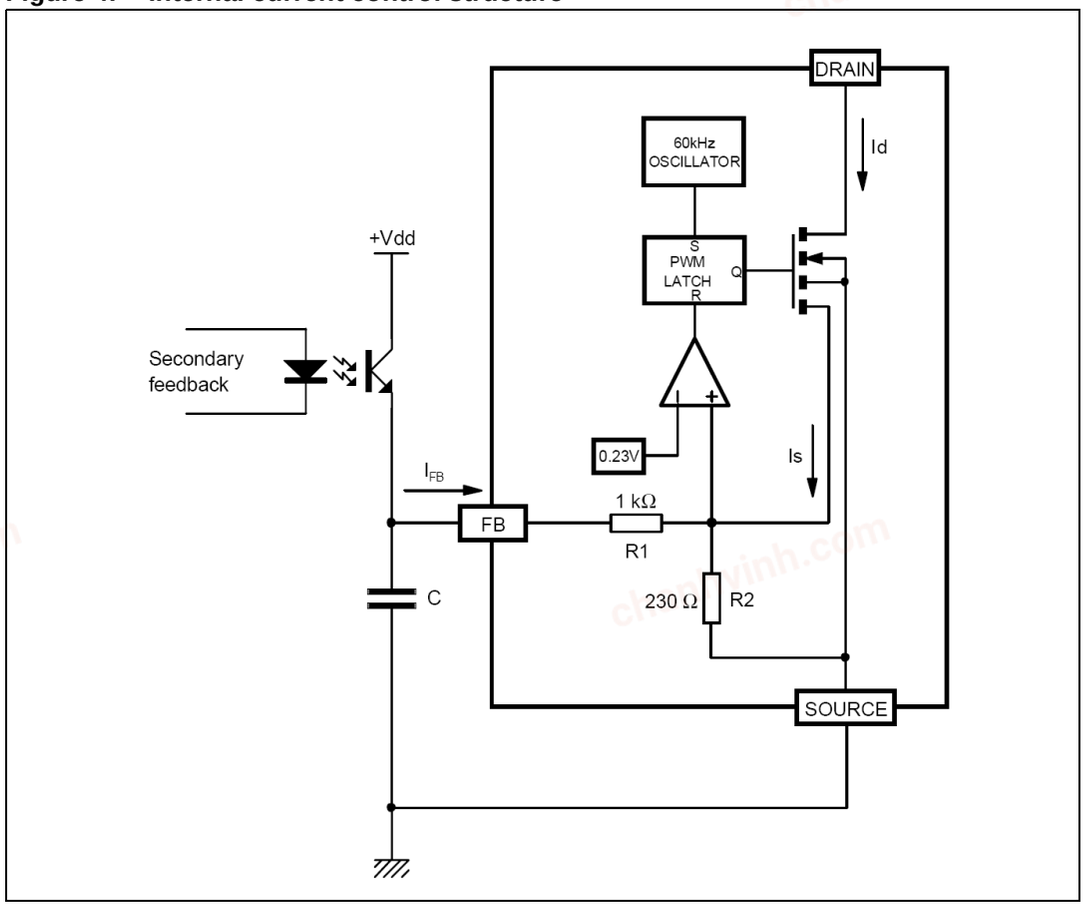
- As soon as the device starts switching, it immediately receives some energy from the auxiliary winding. C5 can be therefore reduced and a small ceramic chip (100nF) is sufficient to insure the filtering function. The total start up time from the switch on of input voltage to output voltage presence is dramatically decreased.
- The output current characteristic can be maintained even with very low or zero output voltage. Since the TSM101 is also supplied in forward mode, it keeps the current regulation up whatever the output voltage is.The V_{DD} pin voltage may vary as much as the input voltage, that is to say with a ratio of about 4 for a wide range application.

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6 Feedback pin principle of operation

A feedback pin controls the operation of the device. Unlike conventional PWM control circuits which use a voltage input (the inverted input of an operational amplifier), the FB pin is sensitive to current. *Figure 4.* presents the internal current mode structure.

Figure 4. Internal current control structure



The Power MOSFET delivers a sense current I_S which is proportional to the main current Id. R2 receives this current and the current coming from the FB pin. The voltage across R2 is then compared to a fixed reference voltage of about 0.23V. The MOSFET is switched off when the following equation is reached:

$$R_2 \cdot (I_S + I_{FB}) = 0.23V$$

By extracting I_S:

$$I_S = \frac{0.23V}{R_2} - I_{FB}$$

Using the current sense ratio of the MOSFET G_{ID}:

$$I_D = G_{ID} \cdot I_S = G_{ID} \cdot \left(\frac{0.23V}{R_2} - I_{FB}\right)$$

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The current limitation is obtained with the FB pin shorted to ground (V_{FB} = 0V). This leads to a negative current sourced by this pin, and expressed by:

$$I_{FB} = -\frac{0.23V}{R_1}$$

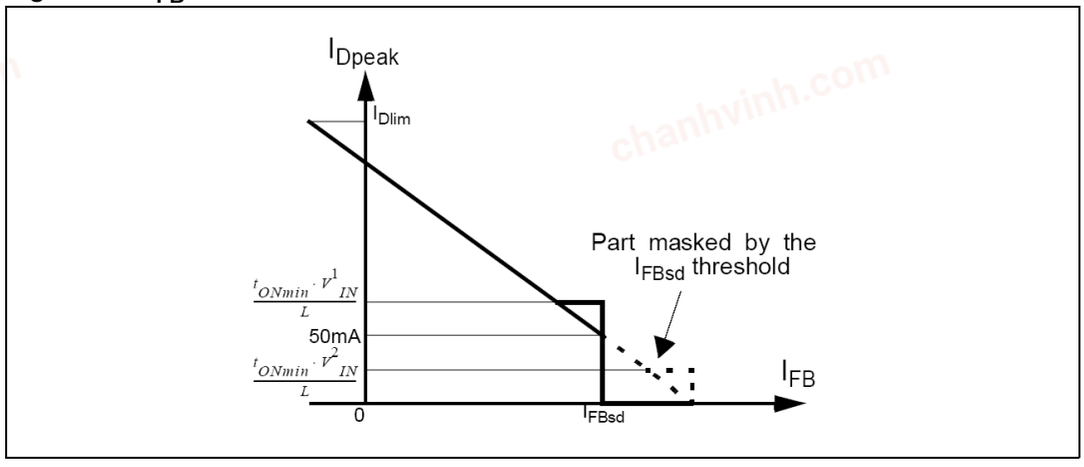
By reporting this expression in the previous one, it is possible to obtain the drain current limitation I_{Dlim}:

$$I_{Dlim} = G_{ID} \cdot 0.23V \cdot \left(\frac{1}{R_2} + \frac{1}{R_1}\right)$$

In a real application, the FB pin is driven with an optocoupler as shown on *Figure 4.* which acts as a pull up. So, it is not possible to really short this pin to ground and the above drain current value is not achievable. Nevertheless, the capacitor C is averaging the voltage on the FB pin, and when the optocoupler is off (start up or short circuit), it can be assumed that the corresponding voltage is very close to 0V.

For low drain currents, the formula (1) is valid as long as IFB satisfies $I_{FB} < I_{FBsd}$, where I_{FBsd} is an internal threshold of the VIPer12A. If I_{FB} exceeds this threshold the device will stop switching. This is represented on *Figure 11 on page 14*, and I_{FBsd} value is specified in the PWM COMPARATOR SECTION. Actually, as soon as the drain current is about 12% of Idlim, that is to say 50 mA, the device will enter a burst mode operation by missing switching cycles. This is especially important when the converter is lightly loaded.

Figure 5. I_{FB} Transfer function

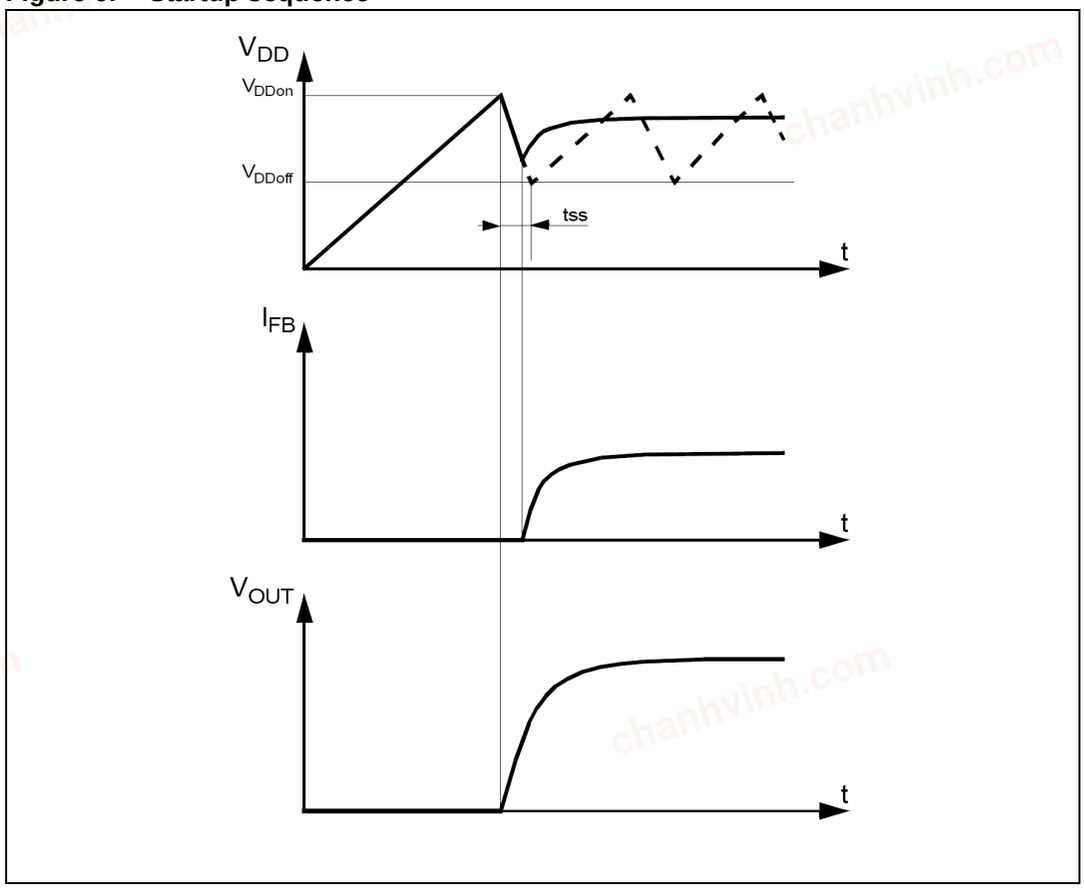


It is then possible to build the total DC transfer function between I_D and I_{FB} as shown on *Figure 5 on page 10*. This figure also takes into account the internal blanking time and its associated minimum turn on time. This imposes a minimum drain current under which the device is no more able to control it in a linear way. This drain current depends on the primary inductance value of the transformer and the input voltage. Two cases may occur, depending on the value of this current versus the fixed 50mA value, as described above.

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7 Startup sequence

Figure 6. Startup sequence



This device includes a high voltage start up current source connected on the drain of the device. As soon as a voltage is applied on the input of the converter, this start up current source is activated as long as V_{DD} is lower than V_{DDon}. When reaching V_{DDon}, the start up current source is switched off and the device begins to operate by turning on and off its main power MOSFET. As the FB pin does not receive any current from the optocoupler, the device operates at full current capacity and the output voltage rises until reaching the regulation point where the secondary loop begins to send a current in the optocoupler. At this point, the converter enters a regulated operation where the FB pin receives the amount of current needed to deliver the right power on secondary side.

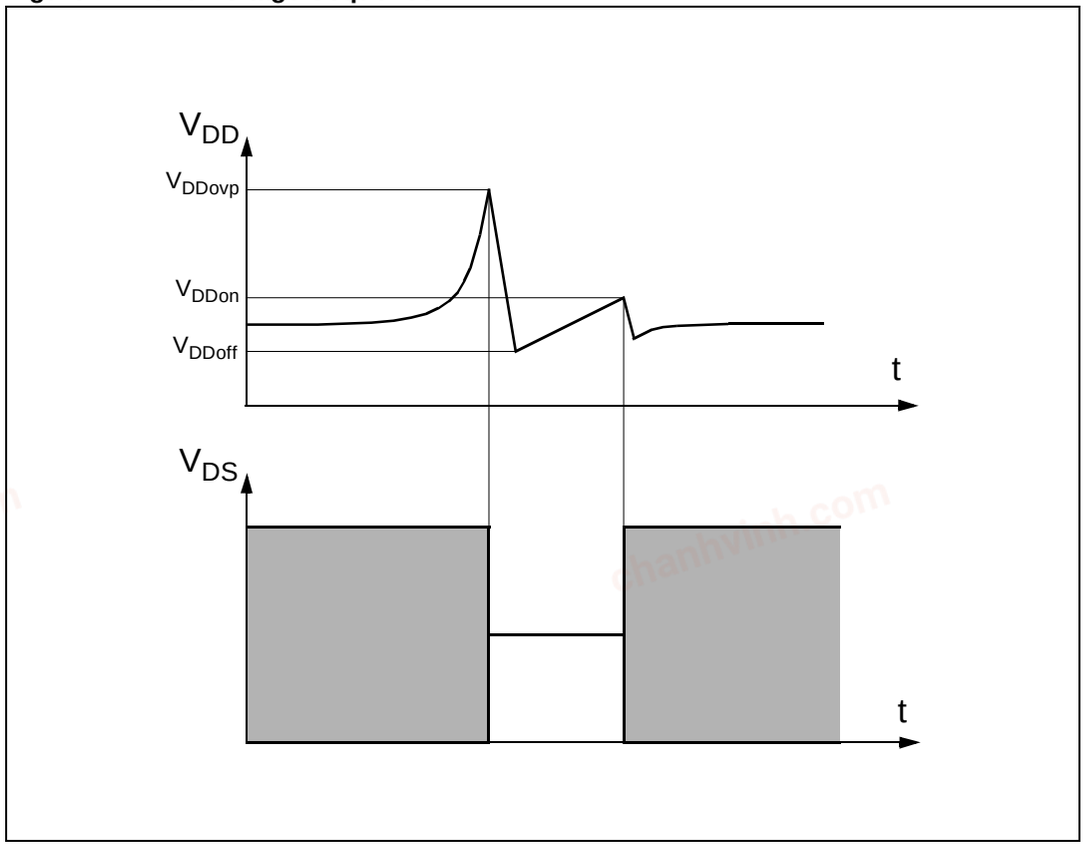
This sequence is shown in *Figure 6*. Note that during the real starting phase t_{ss}, the device consumes some energy from the V_{DD} capacitor, waiting for the auxiliary winding to provide a continuous supply. If the value of this capacitor is too low, the start up phase is terminated before receiving any energy from the auxiliary winding and the converter never starts up. This is illustrated also in the same figure in dashed lines.

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8 Overvoltage threshold

An overvoltage detector on the V_{DD} pin allows the VIPer12A to reset itself when V_{DD} exceeds V_{DDovp}. This is illustrated in *Figure 7.*, which shows the whole sequence of an overvoltage event. Note that this event is only latched for the time needed by V_{DD} to reach V_{DDoff}, and then the device resumes normal operation automatically.

Figure 7. Overvoltage Sequence



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9 Operation pictures

Figure 8. Rise and Fall time

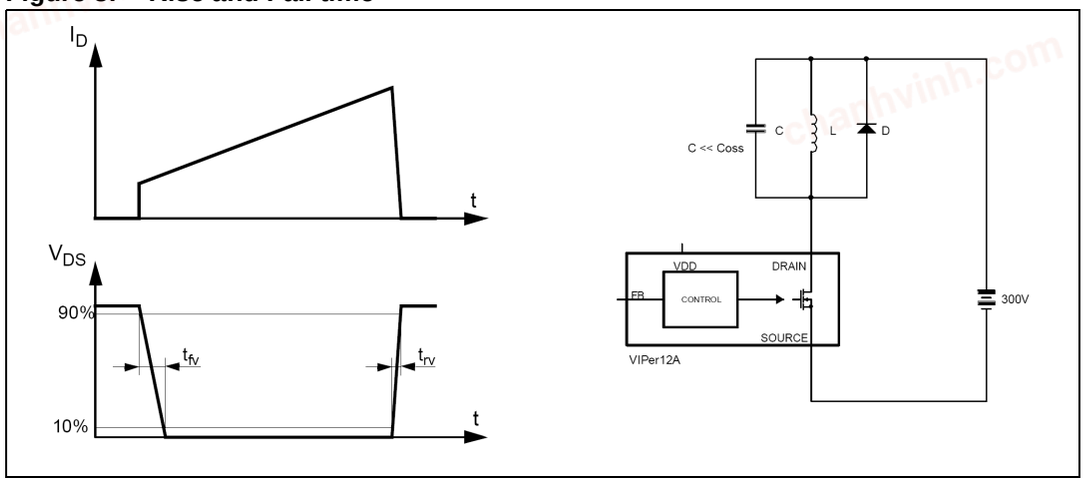


Figure 9. Start-up V_{DD} current

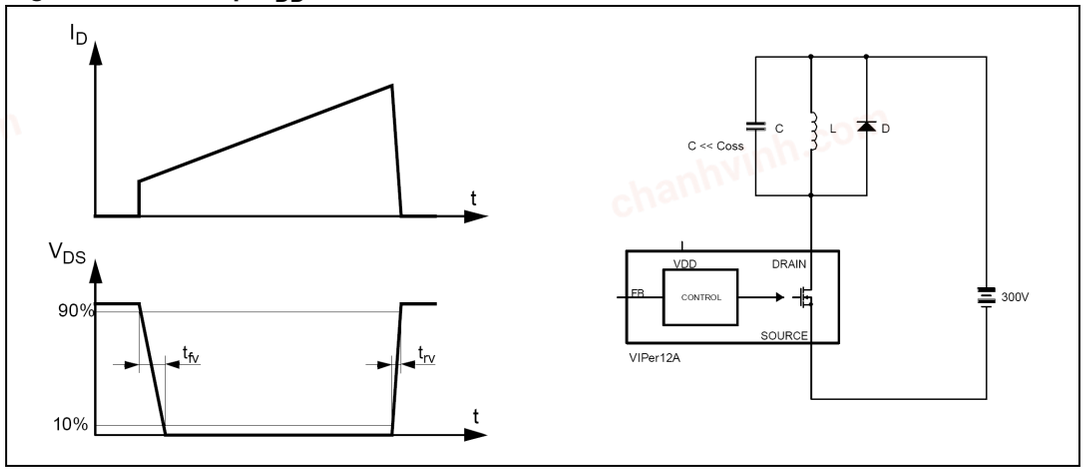
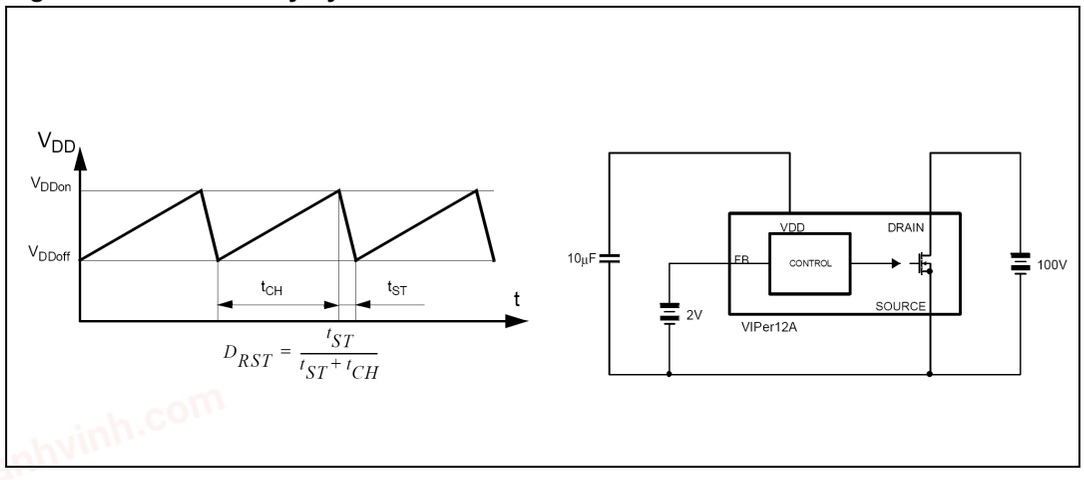


Figure 10. Restart duty-cycle



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Figure 11. Peak drain current Vs. feedback current

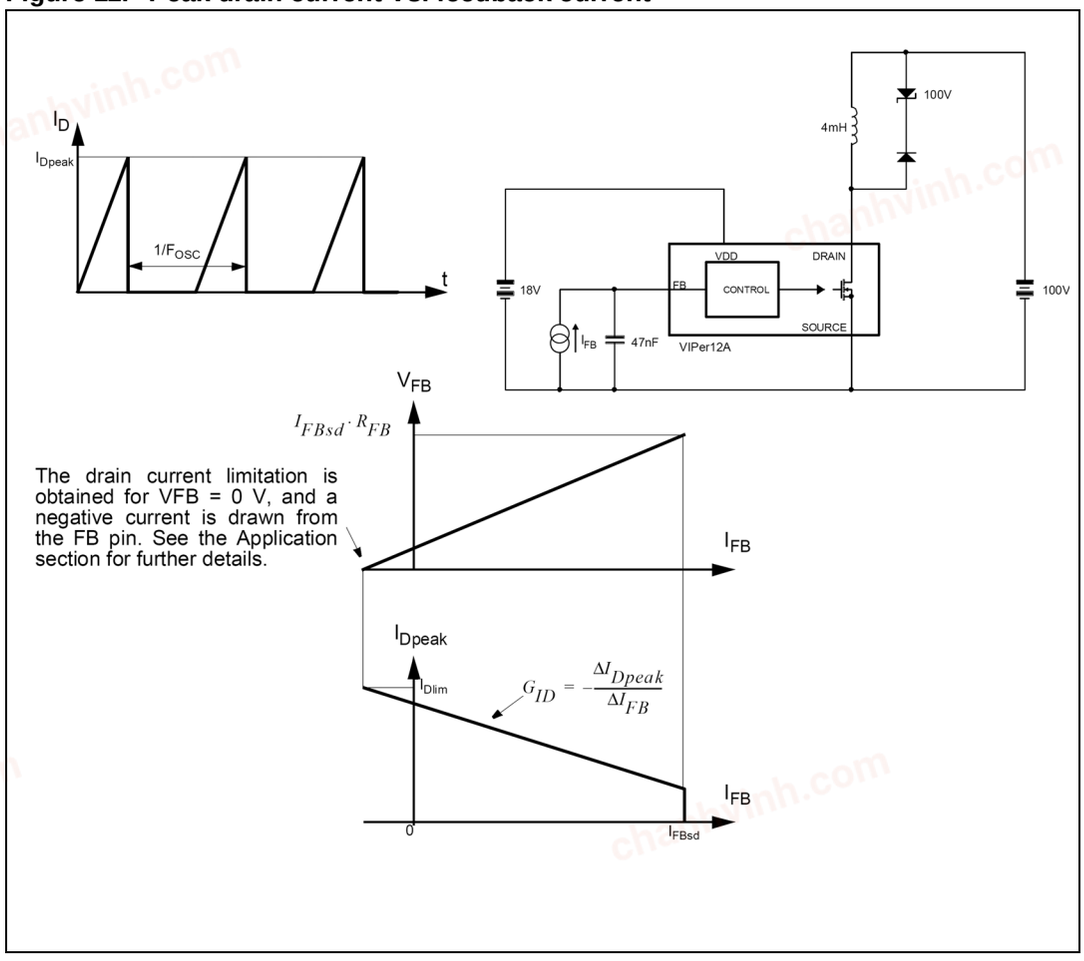
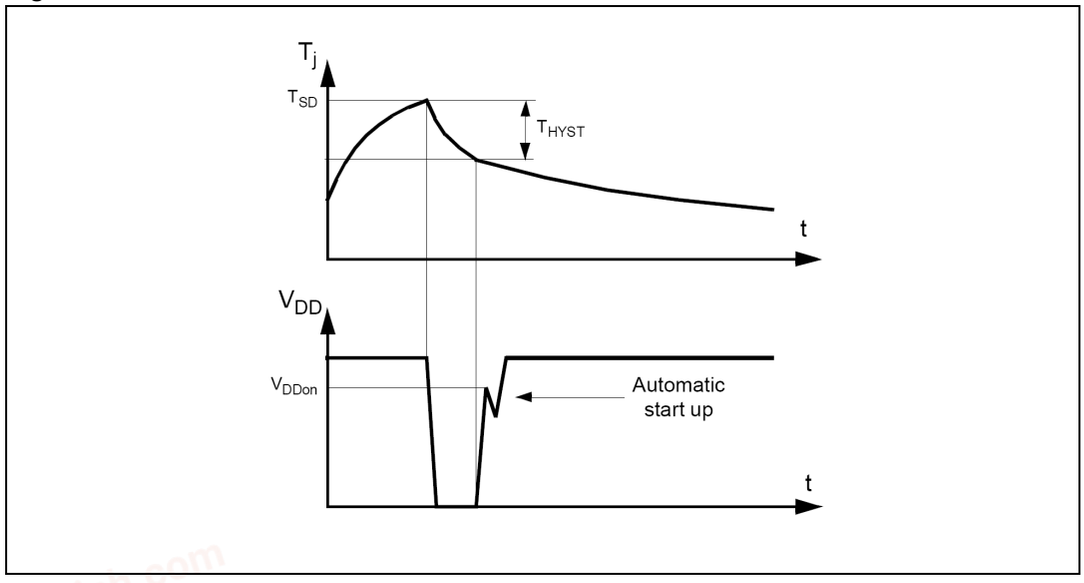


Figure 12. Thermal shutdown



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Figure 13. Switching frequency Vs. temperature

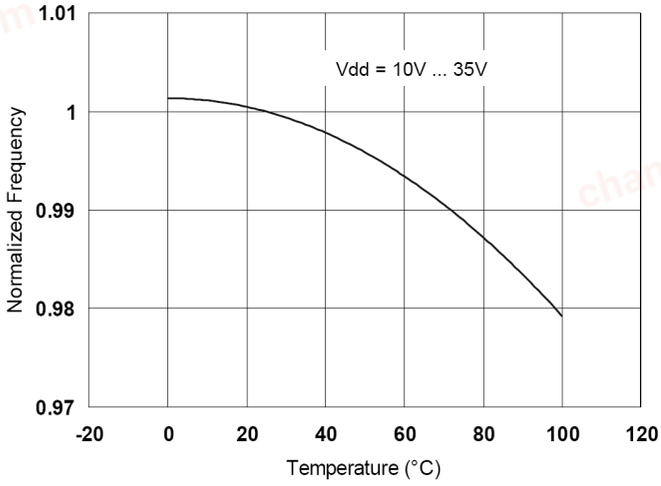
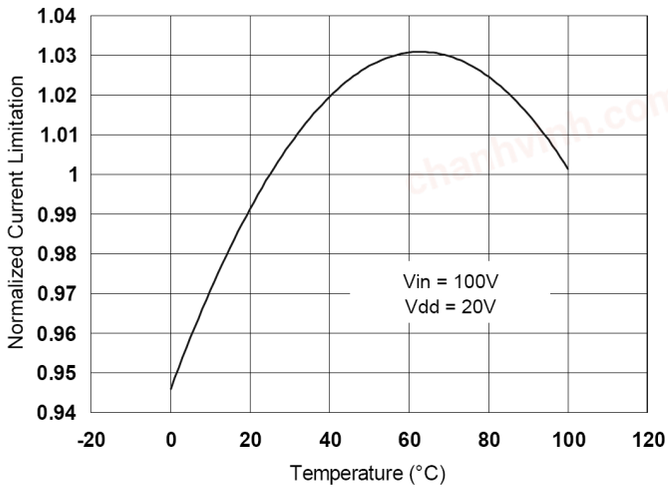


Figure 14. Current Limitation vs. Temperature



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10 Mechanical Data

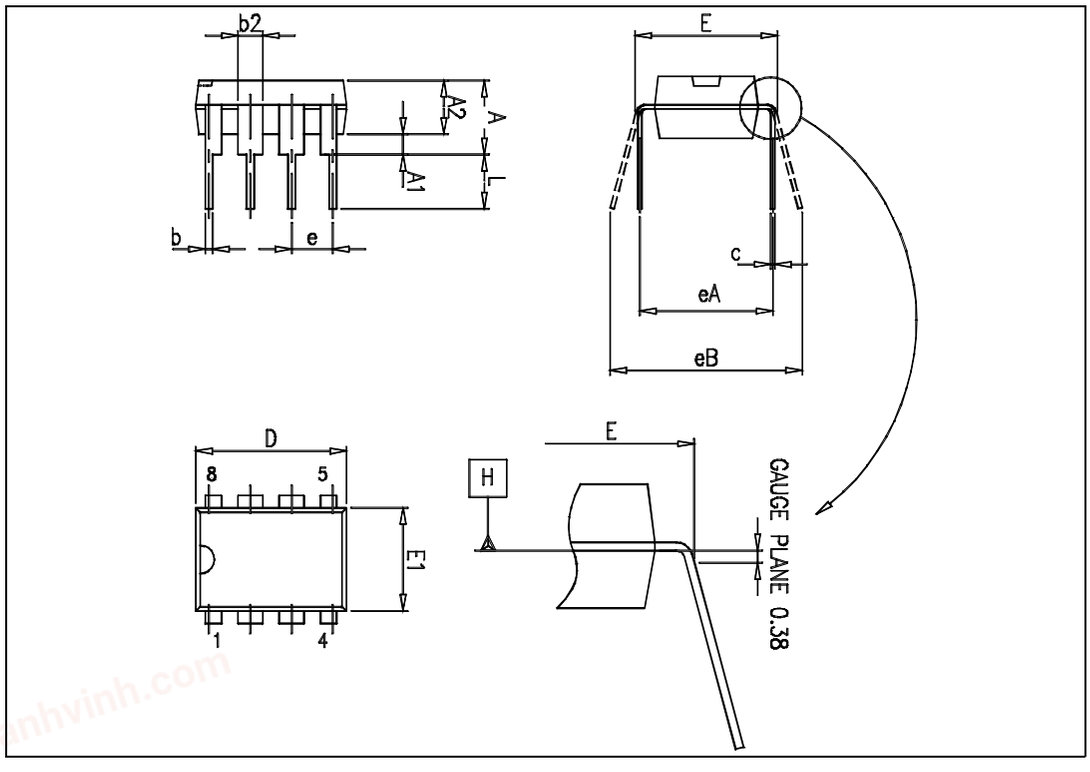
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Table 10. DIP8 Mechanical Data

Dimensions			
Ref.	Databook (mm)		
	Nom.	Min	Max
A			5.33
A1	0.38		
A2	2.92	3.30	4.95
b	0.36	0.46	0.56
b2	1.14	1.52	1.78
c	0.20	0.25	0.36
D	9.02	9.27	10.16
E	7.62	7.87	8.26
E1	6.10	6.35	7.11
e		2.54	
eA		7.62	
eB			10.92
L	2.92	3.30	3.81
Package Weight	Gr. 470		

Figure 15. Package Dimensions

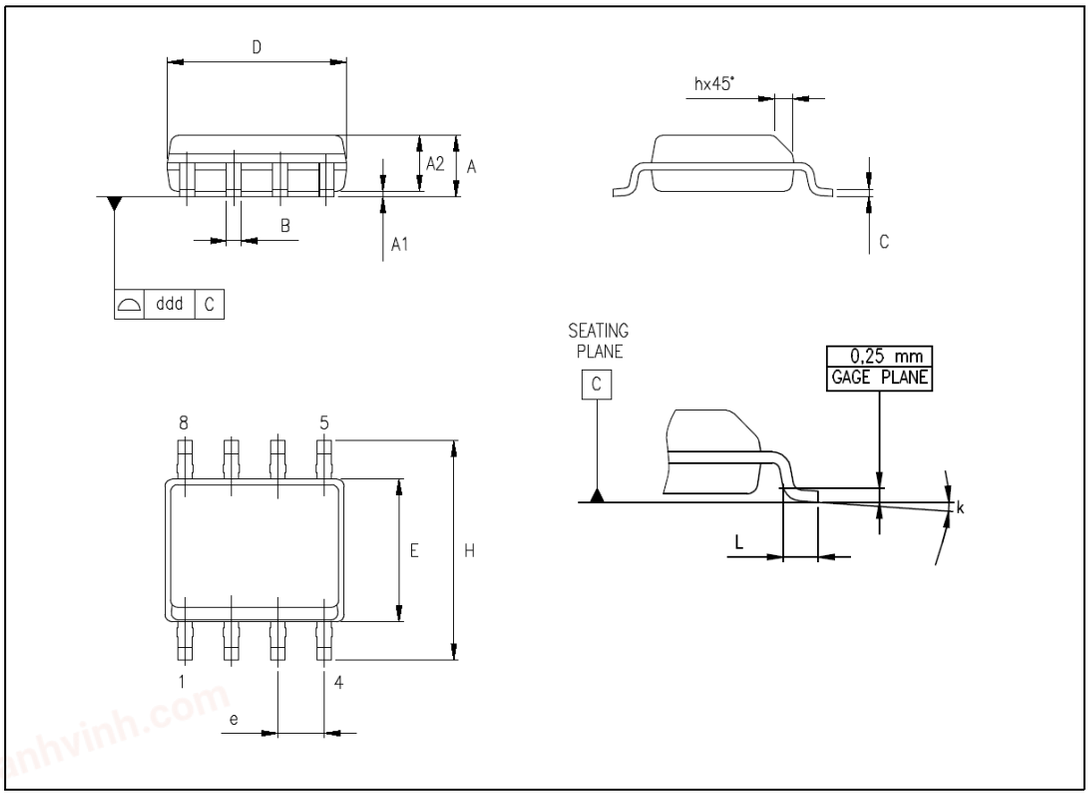


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Table 11. SO8 Mechanical Data

Dimensions			
Ref.	Databook (mm)		
	Nom.	Min	Max
A	1.35		1.75
A1	0.10		0.25
A2	1.10		1.65
B	0.33		0.51
C	0.19		0.25
D	4.80		5.00
E	3.80		4.00
e		1.27	
H	5.80		6.20
h	0.25		0.50
L	0.40		1.27
k	8° (max.)		
ddd			0.1

Figure 16. Package Dimensions



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11 Order codes

Table 12. Order codes

Part Number	Package	Shipment
VIPER12ASTR-E	SO-8	Tape and Reel
VIPer12AS - E	SO-8	Tube
VIPer12ADIP - E	DIP-8	Tube

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12 Revision history

Table 13. Document revision history

Date	Revision	Changes
09-Jan-2006	1	Initial release.

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